

April 2009

# FDP5500\_F085

# **N-Channel UltraFET Power MOSFET** 55V, 80A, $7m\Omega$

#### **Features**

- Typ  $r_{DS(on)}$  = 5.1m $\Omega$  at  $V_{GS}$  = 10V,  $I_D$  = 80A
- Typ  $Q_{g(10)}$  = 114nC at  $V_{GS}$  = 10V
- Simulation Models
  - -Temperature Compensated PSPICE and SABER<sup>TM</sup>
- Peak Current vs Pulse Width Curve
- UIS Rating Curve
- Qualified to AEC Q101
- RoHS Compliant

# **Applications**

- DC Linear Mode Control
- Solenoid and Motor Control
- Switching Regulators
- Automotive Systems

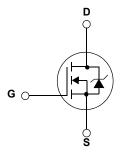


#### DRAIN (FLANGE) SOURCE DRAIN **GATE**

**Package** 

**TO-220AB** 

## Symbol



# **MOSFET Maximum Ratings** $T_C = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Ratings	Units	
$V_{DSS}$	Drain to Source Voltage	(Note 1)	55	V
$V_{DGR}$	Drain to Gate Voltage ( $R_{GS} = 20k\Omega$ ) (Note 1)		55	V
$V_{GS}$	Gate to Source Voltage		±20	V
	Drain Current Continuous (T <sub>C</sub> < 135°C, V <sub>GS</sub> = 10V)		80	А
I <sub>D</sub>	Pulsed		See Figure 4	_ A
E <sub>AS</sub>	Single Pulse Avalanche Energy	(Note 2)	860	mJ
D	Power Dissipation		375	W
$P_D$	Derate above 25°C		2.5	W/°C
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature		-55 to + 175	
T <sub>L</sub>	Max. Lead Temp. for Soldering (at 1.6mm from case for 10sec)		300	°C
T <sub>pkg</sub>	Max. Package Temp. for Soldering (Package Body for 10sec)		260	

### **Thermal Characteristics**

$R_{\theta JC}$	Thermal Resistance Junction to Case	0.4	°C/W
$R_{\theta JA}$	Thermal Resistance Junction to Ambient TO-220AB, 1in <sup>2</sup> copper pad area	62	°C/W

# **Package Marking and Ordering Information**

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDP5500	FDP5500_F085	TO-220AB	Tube	N/A	50 units

# **Electrical Characteristics** $T_C = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units	
Off Cha	racteristics						

B <sub>VDSS</sub>	Drain to Source Breakdown Voltage	$I_D = 250 \mu A, V_{GS} = 0 V$		55	-	-	V
		$V_{DS} = 50V, V_{GS} = 0$	V	-	1	1	цΑ
IDSS Zero Gate Voltage Drain Current	$V_{DS} = 45V$	$T_{\rm C} = 150^{\rm o}{\rm C}$	-	-	250	μΑ	
I <sub>GSS</sub>	Gate to Source Leakage Current	$V_{GS} = \pm 20V$		-	ı	±100	nA

### **On Characteristics**

$V_{GS(th)}$	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = 250 \mu A$	2	2.8	4	V
r <sub>DS(on)</sub>	Drain to Source On Resistance	$I_D = 80A, V_{GS} = 10V$	-	5.1	7	mΩ

## **Dynamic Characteristics**

C <sub>iss</sub>	Input Capacitance	V 05\/ \/	0) (	-	3565	-	pF
Coss	Output Capacitance		$V_{DS}$ = 25V, $V_{GS}$ = 0V, f = 1MHz		1310	-	pF
C <sub>rss</sub>	Reverse Transfer Capacitance	1 - 1101112			395	-	pF
Q <sub>g(TOT)</sub>	Total Gate Charge at 20V	V <sub>GS</sub> = 0 to 20V		-	207	269	nC
Q <sub>g(10)</sub>	Total Gate Charge at 10V	V <sub>GS</sub> = 0 to 10V	$V_{DD} = 30V$	-	114	148	nC
Q <sub>g(TH)</sub>	Threshold Gate Charge	$V_{GS} = 0$ to 2V	$I_D = 80A$ $R_1 = 0.4\Omega$	-	6.6	8.6	nC
Q <sub>gs</sub>	Gate to Source Gate Charge		$I_{c} = 1.0 \text{mA}$	-	17.2	-	nC
Q <sub>gd</sub>	Gate to Drain "Miller" Charge		·g	-	52	-	nC

# **Electrical Characteristics** $T_C = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units

### **Switching Characteristics**

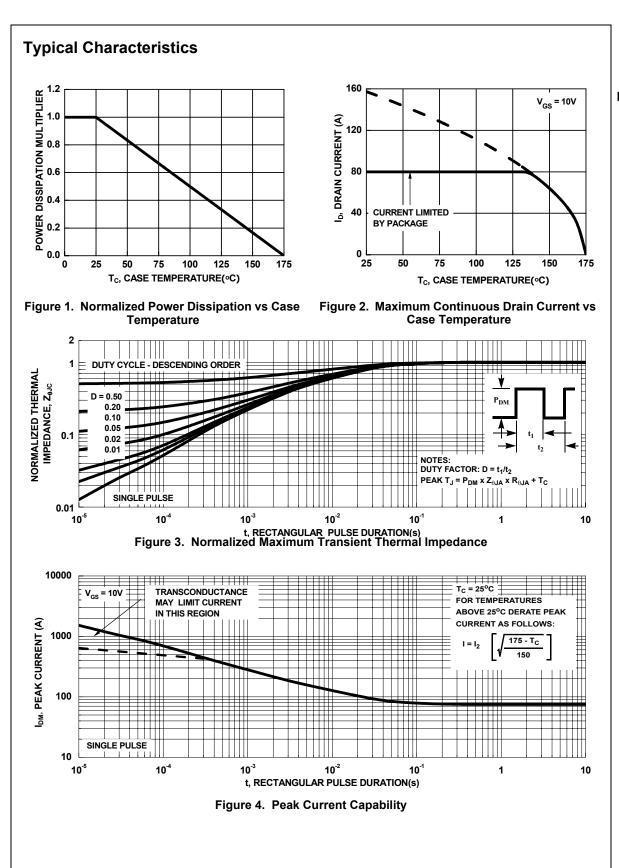
t <sub>on</sub>	Turn-On Time		-	-	75	ns
t <sub>d(on)</sub>	Turn-On Delay Time		1	12	-	ns
t <sub>r</sub>	Rise Time	$V_{DD}$ = 30V, $I_{D}$ = 80A, $R_{L}$ = 0.4 $\Omega$ , $V_{GS}$ = 10V,	-	34	-	ns
t <sub>d(off)</sub>	Turn-Off Delay Time	$R_{\rm L} = 0.4\Omega$ , $V_{\rm GS} = 10V$ , $R_{\rm GS} = 2.5\Omega$	-	37	-	ns
t <sub>f</sub>	Fall Time		-	23	-	ns
t <sub>off</sub>	Turn-Off Time		-	-	96	ns

#### **Drain-Source Diode Characteristics**

$V_{SD}$	Source to Drain Diode Voltage	I <sub>SD</sub> = 80A	-	0.9	1.25	V
t <sub>rr</sub>	Reverse Recovery Time	1 = 804 dl /dt = 1004/	-	58	75	ns
Q <sub>rr</sub>	Reverse Recovery Charge	$I_F = 80A$ , $dI_{SD}/dt = 100A/\mu s$	-	71	92	nC

1: Starting T<sub>J</sub> = 25°C to175°C. 2: Starting T<sub>J</sub> = 25°C, L = 0.42mH, I<sub>AS</sub> = 64A

This product has been designed to meet the extreme test conditions and environment demanded by the automotive industry. For a copy of the requirements, see AEC Q101 at: http://www.aecouncil.com/
All Fairchild Semiconductor products are manufactured, assembled and tested under ISO9000 and QS9000 quality systems certification.



# **Typical Characteristics**

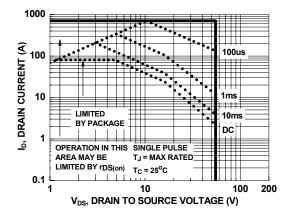
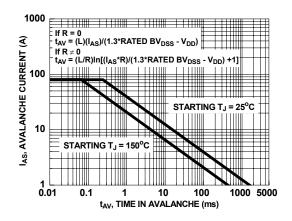


Figure 5. Forward Bias Safe Operating Area



NOTE: Refer to Fairchild Application Notes AN7514 and AN7515 **Figure 6. Unclamped Inductive Switching** 

Capability

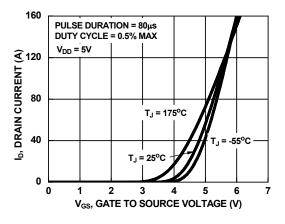


Figure 7. Transfer Characteristics

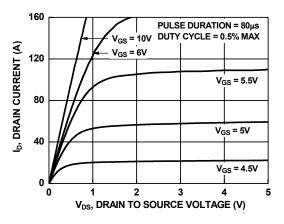


Figure 8. Saturation Characteristics

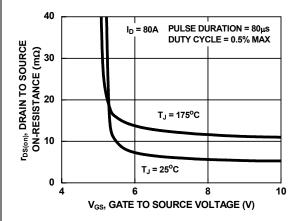


Figure 9. Drain to Source On-Resistance Variation vs Gate to Source Voltage

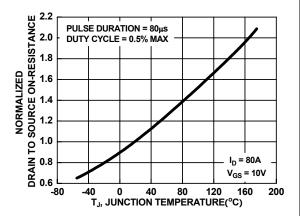


Figure 10. Normalized Drain to Source On Resistance vs Junction Temperature

## **Typical Characteristics**

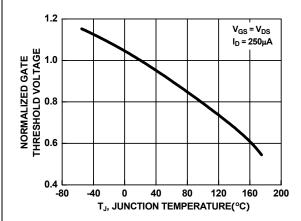


Figure 11. Normalized Gate Threshold Voltage vs
Junction Temperature

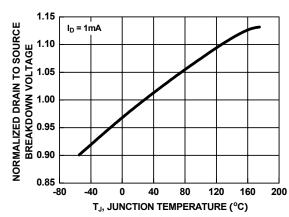


Figure 12. Normalized Drain to Source Breakdown Voltage vs Junction Temperature

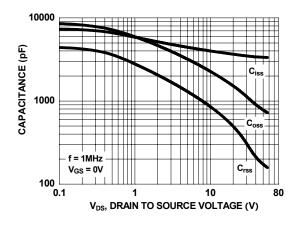


Figure 13. Capacitance vs Drain to Source Voltage

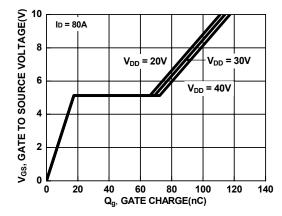


Figure 14. Gate Charge vs Gate to Source Voltage





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